TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE (PCT PROCESS)

# 2 S C 4 4 9 7

### HIGH VOLTAGE CONTROL APPLICATIONS

• High Voltage :  $V_{CBO} = 300V$ ,  $V_{CEO} = 300V$ 

• Low Saturation Voltage: VCE (sat) = 0.5V (Max.)

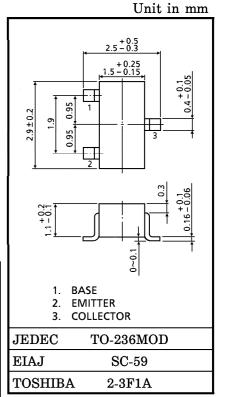
Small Collector Output Capacitance

:  $C_{ob} = 3pF$  (Typ.)

• Complementary to 2SA1721

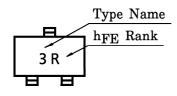
### MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$v_{\mathrm{CBO}}$	300	V
Collector-Emitter Voltage	$v_{CEO}$	300	V
Emitter-Base Voltage	$V_{ m EBO}$	6	V
Collector Current	$^{\mathrm{I}}\mathrm{C}$	100	mA
Base Current	$I_{\mathbf{B}}$	20	mA
Collector Power Dissipation	$P_{\mathbf{C}}$	200	mW
Junction Temperature	$T_{j}$	150	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~150	$^{\circ}\mathrm{C}$



Weight: 0.012g

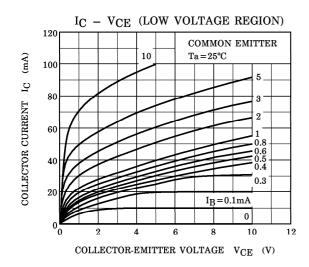
#### **MARKING**

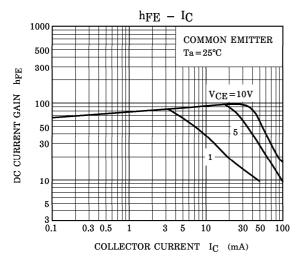


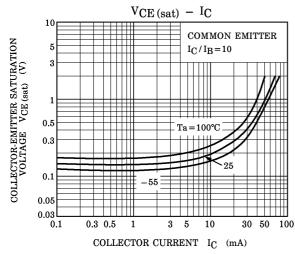
## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

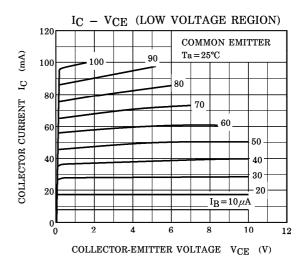
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 300V, I_{E} = 0$	_	_	0.1	$\mu$ A
Emitter Cut-off Current	$I_{ m EBO}$	$V_{EB}=6V, I_C=0$	_	_	0.1	$\mu$ A
Collector-Base Breakdown Voltage	V (BR) CBO	$I_{\rm C} = 0.1 { m mA}, \ I_{\rm E} = 0$	300	_	_	V
Collector-Emitter Breakdown Voltage	V (BR) CEO	$I_C=1$ mA, $I_B=0$	300	_	_	V
DC Current Gain	h <sub>FE (1)</sub> (Note)	$V_{ m CE} = 10 V, I_{ m C} = 20 { m mA}$	30	_	150	
	h <sub>FE (2)</sub>	$V_{CE} = 10V, I_{C} = 1mA$	20	_	_	
Collector-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	$I_C=20$ mA, $I_B=2$ mA	I	_	0.5	V
Base-Emitter Saturation Voltage	V <sub>BE</sub> (sat)	$I_C=20$ mA, $I_B=2$ mA	_	_	1.2	V
Transition Frequency	$ m f_{T}$	$V_{CE} = 10V, I_{C} = 10mA$	_	70	_	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB} = 20V, I_{E} = 0, f = 1MHz$	_	3	4	pF

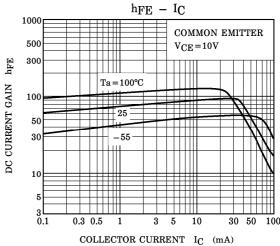
(Note):  $h_{FE(1)}$  Classification  $R:30\sim90$ ,  $O:50\sim150$ 

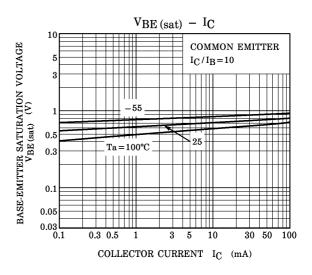


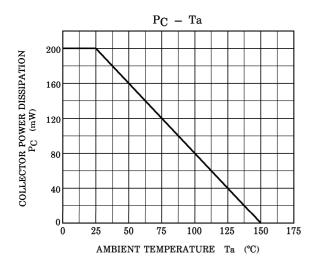












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